



### **TREDI 2017**

# The CT-PPS tracking system with 3D pixel detectors

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# CMS-TOTEM Precision Proton Spectrometer



- The CMS-TOTEM Precision Proton Spectrometer (CT-PPS) allows measurement of protons in the very forward regions on both sides of CMS in standard LHC running conditions, taking advantage of the machine magnets to bend protons
- **Tracking and timing detectors** are placed in Roman pots between 205 and 220 m from the CMS/TOTEM IP, two stations for each detector on both sides





# **Tracking system**



- Requirements:
  - Sustain high radiation levels: for 100 fb<sup>-1</sup>, proton flux up to 5x10<sup>15</sup>/cm<sup>2</sup> in tracking detectors, 10<sup>12</sup> n<sub>eq</sub>/cm<sup>2</sup> and 100 Gy in readout electronics.
  - Small inefficient area at the edge of the sensor toward the beam.
  - Tracking resolution of ~10 μm.
- Baseline design:
  - 3D sensor technology chosen for its intrinsic high radiation hardness and the possibility to implement slim edges.
  - Two stations per side, each with 6 detector planes tilted by 18.4° to increase the cluster size and improve resolution.
  - Readout chip and front-end electronics as for CMS Phase I pixel upgrade.
  - Mechanics and cooling adapted from TOTEM tracking system.



# **Tracking detector - Mechanics**





- 6 detector planes per pot.
- Al support structures produced in Genova.
- Detector heat dissipation provided by a TPG layer encapsulated in a thin aluminium layer connected to a cooling system identical to the TOTEM one.
- Cooling tests showed heat dissipation according to requirements.
  Flex hybrid







# **Tracking detector - Electronics**



- RPix Port Card is custom designed for CT-PPS to interface the tracking station to the readout electronics.
- Concept: TOTEM board (to fit the RP space constraints) with components as in FPIX readout.
- Port Card produced and under final test during this week.





# **3D sensors for CT-PPS**



**3D sensors** produced in the double-sided not-fully passing through technology by CNM Baseline design:

- 2E pixel configuration (2 readout columns)
- 200 µm slim edges
- 2x3 sensors (6 ROCs each)

1E and 2x2 sensors also considered for module production.

# First batch of 3D sensors completed in December 2015.

In general good quality sensors but low yield, in particular of class A ones.

#### Second batch completed in May 2016.

A problem, probably with the p-stop implantation done by an external firm, caused values of breakdown voltage too low for using the sensors. In order to recover the production, a low-dose neutron irradiation ( $\sim 5 \times 10^{13} n_{eq}/cm^2$ ) + annealing has been tried with promising results.

#### Third batch almost completed (March)

#### 36 wafers produced at CNM





# **Module production and tests**



- 3D sensor IV curves measured at CNM on wafer using a temporary metal deposition. Classification and selection of sensors based on these results.
- Bump-bonding at IZM to the PSI46dig ReadOut Chip, same ROC as the CMS Phase I pixel detector upgrade.



- Temporary wire-bonding and gel-pak film gluing on flex hybrid for the module testing and bump-bonding validation with X-ray.
- Precision gluing to final flex hybrid with TPG dissipative layer.
- Module test and calibration in the final assembly.
- Mounting of the 6-planes package.
- Test at SPS H8 beam-line for final validation inside a Roman Pot with cooling and secondary vacuum.



## **Module testing**



# Detectors characterised and optimised in Torino and Genova laboratory:

- IV curve
- ROC calibration and optimisation
- Threshold trimming to ~ 1800 e<sup>-</sup>
- X-ray to check bump-bonding quality

No damage due to flip-chip observed, based on sensor IV curve comparison and ROC performance before and after bump-bonding **Good quality of bump-bonding** checked with X-ray test.













### **Final modules**



Summary of sensors used for the module production (from first batch) 24 modules are needed for the tracking stations

Pixel configuration	Class A	Class B	Class A + B	2E + 1E
3x2 2E	3	10	13	22
3x2 1E	7	2	9	
2x2 2E	4	9	13	24
2x2 1E	6	5	11	
1E (2E): one (two) readout electrode(s) per pixel			Total	46

#### Status of final modules available for assembling:

**3x2 modules:** Tested 22/22 Good modules 18/22 (10 2E) **2x2 modules**: Tested 22/24 Good modules 17/22 (8 2E)

Most of the rejected modules broken during handling or wire-bonding at the beginning of the testing campaign.



### **Beam test - Efficiency**



**10 single-ROC** sensors (**2 1E and 8 2E**) bump-bonded in March at IZM to the CMS Phase I ROC have been **tested at FNAL** with **120 GeV protons**.

Sensors selected both of class A and B.

A telescope with 8 planes of CMS silicon pixel detectors allows to reconstruct tracks with a **resolution of 8 \mum** in both x and y coordinates.

2E (1E) sensors reach the full efficiency already at bias voltages of ~3 V (5 V). No difference in efficiency is seen between class A and B sensors.

Thanks to the not-fully passing-through columns, high efficiency is obtained even without rotating the sensors.

Efficiency greater than 99.4% at 20°. (CT-PPS tracking detector angle = 18.4°)





#### Preliminary

di Fisica Nucleare



Efficiency at the edge of the sensor fitted with a S-curve. Error bars represent the width of the S-curve. Left Edge Efficient Border vs Bias Before Irradiation



At a bias voltage of 40 V up to 150  $\mu$ m can be gained at the edge of the sensor with the 2E layout.

2E detectors allow to gain ~60 μm more than 1E ones at a bias of 40 V thanks to the n<sup>+</sup>-electrode closer to the sensor edge.



# **Beam test - Resolution vs angle**



Detector resolution is evaluated by fitting residuals separately for cluster size 1 and 2. After subtracting the telescope resolution, the **global resolution is obtained as average of the two values weighted by the cluster size probability**.

Since electrodes are closer to the pixel geometrical edge, **2E sensors have more** clusters of size 2 and therefore a better resolution with respect to **1E** ones.



Considering a resolution per single plane between 20 and 25  $\mu$ m, the target resolution of ~10  $\mu$ m can be achieved.





It is foreseen that the detector will be irradiated during its life up to  $5x10^{15}$  p/cm<sup>2</sup> which corresponds to  $\sim 1x10^{15}$  n<sub>eq</sub>/cm<sup>2</sup>.

3 1E CNM + 1 2E SINTEF sensors were irradiated at the CERN IRRAD Proton Facility with 24 GeV protons to fluences of  $1 \times 10^{15}$  and  $3 \times 10^{15}$  n<sub>eq</sub>/cm<sup>2</sup> and tested in a beam at FNAL.

# Results show the advantage of the 2E configuration after irradiation.



#### Efficiency vs Bias After Irradiation Preliminary



X Resolution Weighted vs Angle After Irradiation





# **Test at SPS H8**



Test set-up at H8 very similar to real system in tunnel:

- same LV and HV system
- same slow control
- same DAQ

#### Vacuum and cooling system working properly with:

- p ≈ 0.04 mbar
- T ≈ 25 C

Vacuum and cooling system



#### DAQ system (µTCA)

#### To be inserted in Roman Pot









- During this end-of-the-year LHC shutdown 3D pixel detectors will be installed in the CT-PPS tracking Roman Pots.
- Very good results were obtained at beam tests on single-ROC sensors, both of class A and B.
- **Results, both before and after irradiation, prefer the 2E layout** but also the 1E configuration ensures high efficiency.
- Genova and Torino laboratories have qualified the final modules with very good production yield.
- Tracker mechanics and cooling successfully tested.
- RPix Port Card produced and under final test.
- Final pot assembling under test now at SPS H8.
- Installation in LHC tunnel foreseen in March.



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# Thank you for your attention





# Backup



# **CNM second batch study**



The second batch of 3D sensors had breakdown voltages below the required 25 V. The issue was ascribed to the p-stop implantation done by an external factory.

Low neutron dose irradiation ( $5-10 \times 10^{14} n_{eq}/cm^2$ ) + annealing should help based on other CNM 3D sensor studies. Test on sensors from wafer 11 showed promising results.







Define: Vop = Vdepl +10V

where Vdepl and Vop are respectively the full depletion and operation voltages.

The following specifications, taken at room temperature (20-24  $^\circ\text{C}$ ), qualify a device as functioning correctly:

- Vdepl < 20 V  $\rightarrow$  OK
- Breakdown voltage: Vbd > 35 V
- [I(25V)/I(20V)] < 2
- Current at operation voltage:
  - **Class A** I (Voperation) < 2uA per tile  $\rightarrow$  very good
  - **Class B** 2uA < I (Voperation) < 10uA per tile  $\rightarrow$  good enough
  - **Class C** I (Voperation) > 10uA per tile
- Wafer bow < 200 $\mu$   $\rightarrow$  OK

# **Testbeam at FNAL (T992 collaboration)**





 8 telescope planes of CMS pixel modules (pixel size 100x150 µm<sup>2</sup>), 4 upstream and 4 downstream with respect to the DUTs

TOTEM

- Telescope planes rotated of 25° with respect to 100 μm pixel pitch direction for improving resolution to 8 μm
- Rotation and cooling systems for the DUTs provided by Purdue
- Alignment and analysis software developed at Milano Bicocca





### **Residuals plots**

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- Residuals cluster size 1 are fitted with a square function convoluted with a gaussian.
- Residuals cluster size 2 "Calculated" are evaluated by the charge asymmetry and fitted with a gaussian.

$$\sigma_{\rm CS1} = \sqrt{\left(\frac{width_{\rm CS1}}{\sqrt{12}}\right)^2 + sigma_{\rm CS1}^2 - sigma_{\rm telescope}^2}$$

$$\sigma_{\rm CS2}$$
 =  $\sqrt{\textit{sigma}_{\rm CS2}^2 - \textit{sigma}_{\rm telescope}^2}$ 



# **CT-PPS in the LHC beam line**







# **Experimental challenges**





of normal LHC running, mainly inelastic events overlapping with SD protons from the same bunch crossing

Use **proton timing** for primary vertex determination

Exploit the **kinematical constraints** of CEP events



Proton timing measurement from both sides of CMS allows to determine the primary vertex, correlate it with that of the central detector and reject pile-up

- Time resolution ~10 ps  $\rightarrow$  Vertex z-by-timing: ~2 mm
- Segmentation to cope with the high occupancy expected
- Edgeless (~ 200 µm)
- Radiation hard









Position and angle, combined with the beam magnets, allow to determine the momentum of the scattered proton

- Position resolution of ~10  $\mu m$
- Angular resolution of ~1-2  $\mu rad$
- Slim edges on side facing the beam
  doad region a100 µm
  - $\rightarrow$  dead region ~100  $\mu m$
- Tolerance to inhomogeneous irradiation
  - $\rightarrow$  ~2·10<sup>15</sup> n<sub>eq</sub>/cm<sup>2</sup> close to the beam (for 100 fb<sup>-1</sup>)

**3D silicon pixel detectors** 

Detectors should fit into existing RPs





# **Tracking detectors**



#### 6 detector planes per station

For each plane:



- 16 x 24 mm<sup>2</sup> 3D silicon pixel sensors
- 150(x) x 100(y) µm<sup>2</sup> pixel pattern same as CMS pixel detectors
- 6 PSI46dig readout chips (52x80 pixels each)

Same readout scheme as Phase-I upgrade of CMS Forward Pixel Tracker

→ Existing CMS DAQ components and software reused

**3D sensors** consist of an array of columnar electrodes

Mature technology after ATLAS IBL



#### Interesting features w.r.t. planar sensors:

- Low depletion voltage (~10 V)
- Fast charge collection time
- Reduced charged trapping probability and therefore high radiation hardness
- Slim edges, with dead area of ~100-200 μm or Active edges, with dead area reduced to a few μm
- Spatial resolution comparable with planar detectors



Chosen solution: CNM 3D with inter-electrode distance 62.5 µm (2E – 2 readout columns per pixel)



# Tracker readout system





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